# Voltage Regulator - Dual Low I<sub>Q</sub>, Low Dropout, **Dual Input**

## 300 mA

The NCV8154 is 300 mA, Dual Output Linear Voltage Regulator that offers two independent input pins and provides a very stable and accurate voltage with ultra low noise and very high Power Supply Rejection Ratio (PSRR) suitable for RF applications. The NCV8154 is suitable for powering RF blocks of automotive infotainment systems and other power sensitive device. Due to low power consumption the NCV8154 offers high efficiency and low thermal dissipation.

### Features

- Operating Input Voltage Range: 1.9 V to 5.25 V
- Two Independent Input Voltage Pins
- Two Independent Output Voltage (for detail please refer to Ordering Information)
- Low IQ of typ. 55 µA per Channel
- High PSRR: 75 dB at 1 kHz
- Very Low Dropout: 140 mV Typical at 300 mA
- Thermal Shutdown and Current Limit Protections
- Stable with a 1 µF Ceramic Output Capacitor
- Available in DFN10 3x3mm and WDFN6 1.5x1.5mm Packages
- Active Output Discharge for Fast Output Turn-Off
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable; Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature Range
- These are Pb-free Devices

### **Typical Applications**

- Applications Requiring Wettable Flanks for Enhanced Visual Inspection
- Wireless LAN, Bluetooth<sup>®</sup>, ZigBee<sup>®</sup> Interfaces
- Automotive Infotainment Systems



**Figure 1. Typical Application Schematic** 



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### MARKING DIAGRAMS



See detailed ordering, marking and shipping information on page 16 of this data sheet.



\*Dual IN available only for DFN10 Figure 2. Simplified Schematic Block Diagram

### Table 1. PIN FUNCTION DESCRIPTION – DFN10

Pin No.	Pin Name	Description
1	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.
2	OUT1	Regulated output voltage of the first channel. A small 1 $\mu\text{F}$ ceramic capacitor is needed from this pin to ground to assure stability.
3	OUT2	Regulated output voltage of the second channel. A small 1 $\mu\text{F}$ ceramic capacitor is needed from this pin to ground to assure stability.
4	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.
5,6	N/C	Not connected, can be tied to ground plane to improve thermal dissipation.
7	EN2	Driving EN2 over 0.9 V turns-on OUT2. Driving EN below 0.4 V turns-off the OUT2 and activates the active discharge.
8	IN2	Inputs pin for second channel. It is recommended to connect 1 $\mu$ F ceramic capacitor close to the device pin.
9	IN1	Inputs pin for first channel. It is recommended to connect 1 µF ceramic capacitor close to the device pin.
10	EN1	Driving EN1 over 0.9 V turns-on OUT1. Driving EN below 0.4 V turns-off the OUT1 and activates the active discharge.
_	EXP	Exposed pad must be tied to ground. Soldered to the copper plane allows for effective thermal dissipation.

#### Table 2. PIN FUNCTION DESCRIPTION - WDFN6

Pin No.	Pin Name	Description					
1	EN1	Driving EN1 over 0.9 V turns-on OUT1. Driving EN below 0.4 V turns-off the OUT1.					
2	IN	Inputs pin. It is recommended to connect at least 1 $\mu$ F ceramic capacitor close to the device pin.					
3	EN2	Driving EN2 over 0.9 V turns-on OUT2. Driving EN below 0.4 V turns-off the OUT2.					
4	GND	Power supply ground. Soldered to the copper plane allows for effective heat dissipation.					
5	OUT2	Regulated output voltage of the second channel. A small 1 $\mu\text{F}$ ceramic capacitor is needed from this pin to ground to assure stability.					
6	OUT1	Regulated output voltage of the first channel. A small 1 $\mu$ F ceramic capacitor is needed from this pin to ground to assure stability.					

#### **Table 3. ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	$V_{\rm IN1},V_{\rm IN2}$	–0.3 V to 6 V	V
Output Voltage	V <sub>OUT1</sub> , V <sub>OUT2</sub>	–0.3 V to V <sub>IN</sub> + 0.3 V or 6 V	V
Enable Inputs	V <sub>EN1</sub> , V <sub>EN2</sub>	–0.3 V to V <sub>IN</sub> + 0.3 V or 6 V	V
Output Short Circuit Duration	tsc	Indefinite	S
Operating Ambient Temperature Range	T <sub>A</sub>	-40 to +125	°C
Maximum Junction Temperature	T <sub>J(MAX)</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	–55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD <sub>HBM</sub>	2,000	V
ESD Capability, Machine Model (Note 2)	ESD <sub>MM</sub>	200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)

ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

#### Table 4. THERMAL CHARACTERISTICS (Note 3)

Rating	Symbol	Value	Unit
Thermal Characteristics, DFN10 3 × 3 mm, Thermal Resistance, Junction-to-Air	$\theta_{JA}$	109	°C/W
Thermal Characteristics, WDFN6 1.5 $\times$ 1.5 mm, Thermal Resistance, Junction-to-Air	$\theta_{JA}$	207	°C/W

3. Single component mounted on 1 oz, FR4 PCB with 645 mm<sup>2</sup> Cu area.

#### **RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	Min	Мах	Unit
Input Voltage	V <sub>IN</sub>	1.9	5.25	V
Junction Temperature	TJ	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### **Table 5. ELECTRICAL CHARACTERISTICS**

 $(-40^{\circ}C \le T_J \le 125^{\circ}C; V_{IN} = V_{OUT(NOM)} + 1 \text{ V or } 2.5 \text{ V}$ , whichever is greater;  $V_{EN} = 0.9 \text{ V}$ ,  $I_{OUT} = 1 \text{ mA}$ ,  $C_{IN} = C_{OUT} = 1 \mu \text{F}$ . Typical values are at  $T_J = +25^{\circ}C$ . Min/Max values are specified for  $T_J = -40^{\circ}C$  and  $T_J = 125^{\circ}C$  respectively.) (Note 4)

Parameter	Test Conditions			Symbol	Min	Тур	Max	Unit
Operating Input Voltage	ting Input Voltage		V <sub>IN</sub>	1.9		5.25	V	
	1000 ( T ) ( 10500	V <sub>OUT</sub> > 2 \	/	V <sub>OUT</sub>	-3		+3	%
Output Voltage Accuracy	$-40^{\circ}C \le T_J \le 125^{\circ}C$	$V_{OUT} \le 2 V$			-60		+60	mV
Line Regulation	$V_{OUT} + 0.5 \text{ V} \leq V_{IN} \leq 5 \text{ V}$			Reg <sub>LINE</sub>		0.02	0.2	%/V
Load Degulation	1 mA to 200 mA		DFN10	Dec		15	40	mV
Load Regulation	I <sub>OUT</sub> = 1 mA to 300 mA		WDFN6	Reg <sub>LOAD</sub>		25	45	mv
		V <sub>OUT(nom)</sub> :	= 1.8 V			335	430	mV
Dropout Voltage (Note 5)	I <sub>OUT</sub> = 300 mA	V <sub>OUT(nom)</sub> :	= 2.8 V	$V_{DO}$		160	290	
		V <sub>OUT(nom)</sub> :	= 3.3 V			140	270	
Output Current Limit	V <sub>OUT</sub> = 90% V <sub>OUT(nom)</sub>			I <sub>CL</sub>		400		mA
Quiescent Current	$I_{OUT}$ = 0 mA, EN1 = V_{IN}, EN2 = 0 V or EN2 = V_{IN}, EN1 = 0 V			Ι <sub>Q</sub>		55	100	μA
	$I_{OUT1} = I_{OUT2} = 0$ mA, $V_{EN1} = V_{EN2} = V_{IN}$			Ι <sub>Q</sub>		110	200	
Shutdown current (Note 6)	$V_{EN}$ $\leq$ 0.4 V, $V_{IN}$ = 5.25 V			I <sub>DIS</sub>		0.1	1	μA
EN Pin Threshold Voltage High Threshold Low Threshold	V <sub>EN</sub> Voltage increasing V <sub>EN</sub> Voltage decreasing			V <sub>EN_HI</sub> V <sub>EN_LO</sub>	0.9		0.4	V
EN Pin Input Current	V <sub>EN</sub> = V <sub>IN</sub> = 5.25 V			I <sub>EN</sub>		0.3	1.0	μΑ
Power Supply Rejection Ratio	$ \begin{array}{l} V_{IN} = V_{OUT} + 1 \ V \ \text{for} \ V_{OUT} > 2 \ V, \ V_{IN} = \\ 2.5 \ V, \ \text{for} \ V_{OUT} \leq 2 \ V, \ I_{OUT} = 10 \ \text{mA} \end{array} \  \  f = 1 \ \text{kHz} $			PSRR		75		dB
Output Noise Voltage	f = 10 Hz to 100 kHz			V <sub>N</sub>		75		$\mu V_{rms}$
Active Discharge Resistance	V <sub>IN</sub> = 4 V, V <sub>EN</sub> < 0.4 V			R <sub>DIS</sub>		50		Ω
Thermal Shutdown Temperature	Temperature increasing from $T_J = +25^{\circ}C$			T <sub>SD</sub>		160		°C
Thermal Shutdown Hysteresis	Temperature falling from T <sub>SD</sub>			T <sub>SDH</sub>	_	20	-	°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
Characterized when V<sub>OUT</sub> falls 100 mV below the regulated voltage at V<sub>IN</sub> = V<sub>OUT(NOM)</sub> + 1 V.
Shutdown Current is the current flowing into the IN pin when the device is in the disable state.









Figure 24. Output Voltage Noise Spectral Density for V<sub>OUT</sub> = 2.8 V, C<sub>OUT</sub> = 1  $\mu$ F





	RMS Output Noise (μV)			
IOUT	10 Hz – 100 kHz	100 Hz – 100 kHz		
1 mA	119.7	117.87		
10 mA	113.47	111.47		
150 mA	113.84	112.05		
300 mA	115.95	114.03		









Figure 36. Load Transient Response – 1.8 V – Rising Edge, I<sub>OUT1</sub> = 100 μA to 300 mA









Figure 37. Load Transient Response – 1.8 V – Falling Edge, I<sub>OUT1</sub> = 300 mA to 100 μA



Figure 39. Load Transient Response – 1.8 V – Falling Edge, I<sub>OUT1</sub> = 300 mA to 1 mA



Edge,  $I_{OUT} = 300$  mA to 50 mA













Figure 43. Load Transient Response – 3.3 V – Falling Edge, I<sub>OUT1</sub> = 300 mA to 100 μA



Figure 45. Load Transient Response – 3.3 V – Falling Edge, I<sub>OUT1</sub> = 300 mA to 1 mA







Shutdown

#### General

The NCV8154 is a dual output high performance 300 mA Low Dropout Linear Regulator. This device delivers very high PSRR (75 dB at 1 kHz) and excellent dynamic performance as load/line transients. In connection with low quiescent current this device is very suitable for various battery powered applications such as tablets, cellular phones, wireless and many others. Each output is fully protected in case of output overload, output short circuit condition and overheating, assuring a very robust design. The NCV8154 device is housed in DFN10 3 x3 mm package which is useful for space constrains application.

#### Input Capacitor Selection (CIN)

It is recommended to connect at least a 1  $\mu$ F Ceramic X5R or X7R capacitor as close as possible to the IN pin of the device. This capacitor will provide a low impedance path for unwanted AC signals or noise modulated onto constant input voltage. There is no requirement for the min. or max. ESR of the input capacitor but it is recommended to use ceramic capacitors for their low ESR and ESL. A good input capacitor will limit the influence of input trace inductance and source resistance during sudden load current changes. Larger input capacitor may be necessary if fast and large load transients are encountered in the application.

#### Output Decoupling (C<sub>OUT</sub>)

The NCV8154 requires an output capacitor for each output connected as close as possible to the output pin of the regulator. The recommended capacitor value is 1  $\mu$ F and X7R or X5R dielectric due to its low capacitance variations over the specified temperature range. The NCV8154 is designed to remain stable with minimum effective capacitance of 0.33  $\mu$ F to account for changes with temperature, DC bias and package size. Especially for small package size capacitors such as 0201 the effective capacitance drops rapidly with the applied DC bias.

There is no requirement for the minimum value of Equivalent Series Resistance (ESR) for the  $C_{OUT}$  but the maximum value of ESR should be less than 3  $\Omega$ . Larger output capacitors and lower ESR could improve the load transient response or high frequency PSRR. It is not recommended to use tantalum capacitors on the output due to their large ESR. The equivalent series resistance of tantalum capacitors is also strongly dependent on the temperature, increasing at low temperature.

#### **Enable Operation**

The NCV8154 uses the dedicated EN pin for each output channel. This feature allows driving outputs separately.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned–off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active so that the output voltage  $V_{OUT}$ is pulled to GND through a 50  $\Omega$  resistor. In the disable state the device consumes as low as typ. 10 nA from the V<sub>IN</sub>. If the EN pin voltage >0.9 V the device is guaranteed to be enabled. The NCV8154 regulates the output voltage and the active discharge transistor is turned–off.

The both EN pin has internal pull-down current source with typ. value of 300 nA which assures that the device is turned-off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN.

#### **Output Current Limit**

Output Current is internally limited within the IC to a typical 400 mA. The NCV8154 will source this amount of current measured with a voltage drops on the 90% of the nominal  $V_{OUT}$ . If the Output Voltage is directly shorted to ground ( $V_{OUT} = 0$  V), the short circuit protection will limit the output current to 520 mA (typ). The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration. This protection works separately for each channel. Short circuit on the one channel do not influence second channel which will work according to specification.

#### **Thermal Shutdown**

When the die temperature exceeds the Thermal Shutdown threshold ( $T_{SD} - 160^{\circ}$ C typical), Thermal Shutdown event is detected and the affected channel is turn-off. Second channel still working. The channel which is overheated will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold ( $T_{SDU} - 140^{\circ}$ C typical). Once the device temperature falls below the 140°C the appropriate channel is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking. The long duration of the short circuit condition to some output channel could cause turn-off other output when heat sinking is not enough and temperature of the other output reach  $T_{SD}$  temperature.

#### **Power Dissipation**

As power dissipated in the NCV8154 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation, junction temperature should be limited to  $+125^{\circ}$ C.

The maximum power dissipation the NCV8154 can handle is given by:

$$\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = \frac{\left[\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}\right]}{\theta_{\mathsf{J}\mathsf{A}}} \qquad (\text{eq. 1})$$

The power dissipated by the NCV8154 for given application conditions can be calculated from the following equations:





Figure 53.  $\theta_{JA}$  and  $P_{D(MAX)}$  vs. Copper Area – WDFN6

#### **Reverse Current**

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that  $V_{OUT} > V_{IN}$ . Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

#### **Power Supply Rejection Ratio**

The NCV8154 features very good Power Supply Rejection ratio. If desired the PSRR at higher frequencies in the range 100 kHz - 10 MHz can be tuned by the selection of COUT capacitor and proper PCB layout.

#### Turn-On Time

The turn-on time is defined as the time period from EN assertion to the point in which VOUT will reach 98% of its nominal value. This time is dependent on various application conditions such as V<sub>OUT(NOM)</sub>, C<sub>OUT</sub>, T<sub>A</sub>.

#### **PCB Layout Recommendations**

To obtain good transient performance and good regulation characteristics place input and output capacitors close to the device pins and make the PCB traces wide. In order to minimize the solution size, use 0402 capacitors. Larger copper area connected to the pins will also improve the device thermal resistance. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad should be tied the shortest path to the GND pin.

#### Table 6. ORDERING INFORMATION

Device	Marking	Voltage Option (OUT1/OUT2)	Active Discharge	Features	Package	Shipping <sup>†</sup>	
NCV8154MW120180TBG	8154W 1218	1.2 V / 1.8 V	Yes				
NCV8154MW120280TBG	8154W 1228	1.2 V / 2.8 V	Yes	-			
NCV8154MW150180TBG	8154W 1518	1.5 V / 1.8 V	Yes			3000 / Tape & Reel	
NCV8154MW150330TBG	8154W 1533	1.5 V / 3.3 V	Yes	Wettable Flank	DFN10 (Pb-Free)		
NCV8154MW180250TBG	8154W 1825	1.8 V / 2.5 V	Yes				
NCV8154MW180280TBG	8154W 1828	1.8 V / 2.8 V	Yes	Non-wettable Flank			
NCV8154MW280120TBG	8154W 2812	2.8 V / 1.2 V	Yes				
NCV8154MN300300TBG	8154N 3030	0.01/ (0.01/	Yes				
NCV8154MW300300TBG	8154W 3030	3.0 V / 3.0 V	Yes	Wettable Flank			
NCV8154MN330180TBG	8154N 3318	0.01///.01/	Yes	Non-wettable Flank			
NCV8154MW330180TBG	8154W 3318	3.3 V / 1.8 V	Yes	Wettable Flank			
NCV8154MW330280TBG	8154W 3328	3.3 V / 2.8 V	Yes				
NCV8154MW330330TBG	8154W 3333	3.3 V / 3.3 V	Yes	- Wettable Flank			
NCV8154MTW180280TCG	DA	1.8 V / 2.8 V	No	Wettable Flank	WDFN6 (Pb-Free)	3000 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.









\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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